NSN 5961-01-029-9691

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Inclosure Material:

Glass and metal

Overall Length:

0.440 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-61

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Overall Width Across Flats:

0.687 inches

Thread Size:

0.250 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

120.0 collector to base voltage, dc and 8.0 emitter to base voltage, dc and 100.0 collector to emitter voltage, dc

Current Rating Per Characteristic:

10.00 amperes source cutoff current

Power Rating Per Characteristic:

50.0 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Thread Series Designator:

Unf

Terminal Type And Quantity:

3 tab, solder lug

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0